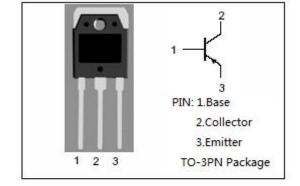


isc Silicon PNP Power Transistor

TIP36B

DESCRIPTION

- · DC Current Gain-
 - : $h_{FE} = 25(Min)@I_C = -1.5A$
- · Collector-Emitter Sustaining Voltage-
 - : V_{CEO(SUS)}= -80V(Min)
- Complement to Type TIP35B
- · Current Gain-Bandwidth Product-
 - : f_T = 3.0MHz(Min)@ I_C = -1.0A
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



mm

APPLICATIONS

 Designed for use in general purpose power amplifier and switching applications.

ABSOLUTE MAXIMUM RATINGS (T_a=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V _{CBO}	Collector-Base Voltage	-80	V
V _{CEO}	Collector-Emitter Voltage	-80	V
V _{EBO}	Emitter-Base Voltage	-5	V
Ic	Collector Current-Continuous	-25	Α
Ісм	Collector Current-peak	-40	Α
I _B	Base Current	-5	Α
Pc	Collector Power Dissipation@Tc=25°C	125	W
Tj	Junction Temperature	150	$^{\circ}$
T _{stg}	Storage Temperature Range	-65~150	$^{\circ}$

DIM MIN MAX 19.60 20.30 A 15.50 15.70 В 4.70 1.90 3.40 2.90 THERMAL CHARACTERISTICS R **SYMBOL PARAMETER** MAX UNIT 5.90 9.90 °C/W Thermal Resistance, Junction to Case 1.0 R_{th j-c}



isc Silicon PNP Power Transistor

TIP36B

ELECTRICAL CHARACTERISTICS

T_c=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V _{CEO(SUS)}	Collector-Emitter Sustaining Voltage	I _C = -30mA ;I _B = 0	-80		V
VCE(sat)-1	Collector-Emitter Saturation Voltage	I _C = -15A ;I _B = -1.5A		-1.8	V
VCE(sat)-2	Collector-Emitter Saturation Voltage	I _C = -25A; I _B = -5A		-4.0	V
VBE(on)-1	Base-Emitter On Voltage	I _C = -15A ; V _{CE} = -4V		-2.0	V
V _{BE(on)-2}	Base-Emitter On Voltage	I _C = -25A ; V _{CE} = -4V		-4.0	V
I _{CEO}	Collector Cutoff Current	V _{CE} = -60V; I _B = 0		-1.0	mA
I _{CBO}	Collector Cutoff Current	V _{CB} = -80V; I _E = 0		-0.7	mA
І _{ЕВО}	Emitter Cutoff Current	V _{EB} = -5V; I _C = 0		-1.0	mA
h _{FE-1}	DC Current Gain	I _C = -1.5A; V _{CE} = -4V	25		
h _{FE-2}	DC Current Gain	I _C = -15A ; V _{CE} = -4V	15	75	
f⊤	Current-Gain—Bandwidth Product	I _C = -1A; V _{CE} = -10V;f _{test} = 1.0MHz	3		MHz

NOTICE:

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